ASSP

Dual Serial Input PLL Frequency Synthesizer

MB15F74UL

DESCRIPTION

The Fujitsu MB15F74UL is a serial input Phase Locked Loop (PLL) frequency synthesizer with a 4000 MHz and a 2000 MHz prescalers. A 64/65 or a 128/129 for the 4000 MHz prescaler, and a 32/33 or a 64/65 for the 2000 MHz prescaler can be selected for the prescaler that enables pulse swallow operation.

The BiCMOS process is used, as a result a supply current is typically 9.0 mA at 3.0 V. The supply voltage range is from 2.7 V to 3.6 V. A refined charge pump supplies well-balanced output current with 1.5 mA and 6 mA selectable by serial date. The pin assignments are the same as MB15F78UL. Fast locking is achieved for adopting the new circuit.

The new package (BCC20) decreases a mount area of MB15F74UL more than 30% comparing with the former BCC16 (for dual PLL) .

FEATURES

- High frequency operation
- : RF synthesizer : 4000 MHz Max

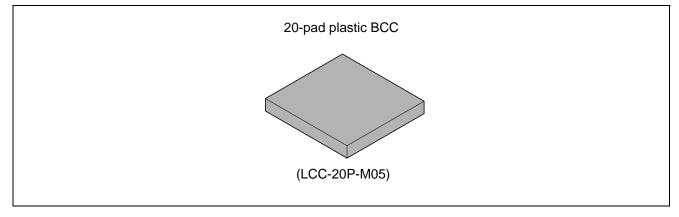
: Vcc = 2.7 to 3.6 V

- : IF synthesizer : 2000 MHz Max
- Low power supply voltage
- Ultra low power supply current : Icc = 9.0 mA Typ

 $(V_{CC} = V_P = 3.0 \text{ V}, \text{ Ta} = +25 \text{ °C}, \text{ SW}_{IF} = \text{SW}_{RF} = 0 \text{ in IF/RF locking state})$

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PACKAGE





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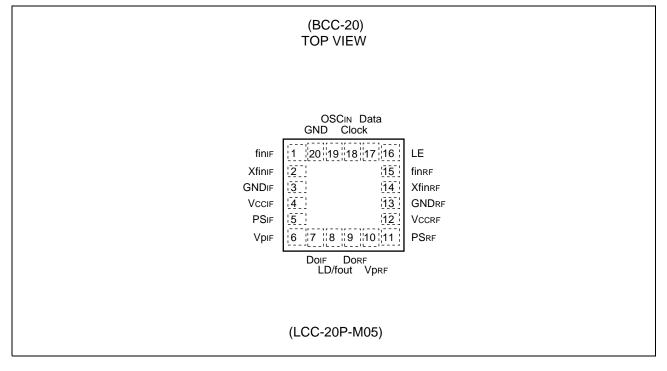
• Direct power saving function : Power supply current in power saving mode

Typ 0.1 μA (Vcc = Vp = 3.0 V, Ta = +25 °C)

Max 10 μ A (Vcc = Vp = 3.0 V)

- Software selectable charge pump current : 1.5 mA/6.0 mA Typ
- Dual modulus prescaler : 4000 MHz prescaler (64/65 or128/129) /2000 MHz prescaler (32/33 or 64/65)
- 23 bit shift register
- Serial input binary 14-bit programmable reference divider : R = 3 to 16,383
- Serial input programmable divider consisting of:
 - Binary 7-bit swallow counter : 0 to 127
 - Binary 11-bit programmable counter : 3 to 2,047
- Built-in high-speed tuning, low-noise phase comparator, current-switching type constant current circuit
- On-chip phase control for phase comparator
- On-chip phase comparator for fast lock and low noise
- Built-in digital locking detector circuit to detect PLL locking and unlocking
- Operating temperature : Ta = $-40 \degree C$ to $+85 \degree C$

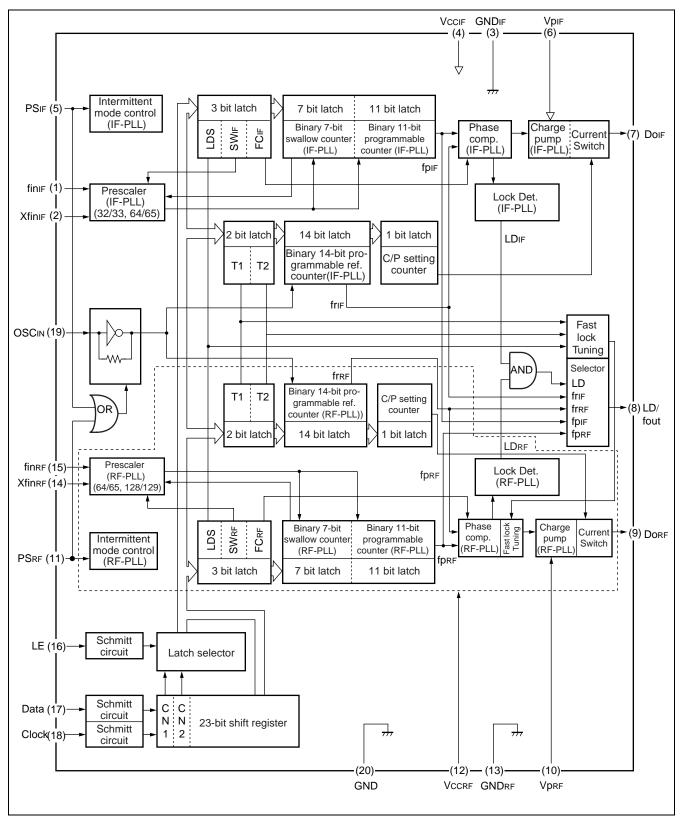
■ PIN ASSIGNMENTS



■ PIN DESCRIPTION

Pin no.	Pin name	I/O	Descriptions
1	fin⊧	I	Prescaler input pin for the IF-PLL. Connection to an external VCO should be AC coupling.
2	Xfinı⊧	I	Prescaler complimentary input for the IF-PLL section. This pin should be grounded via a capacitor.
3	GNDIF		Ground pin for the IF-PLL section.
4	Vccif		Power supply voltage input pin for the IF-PLL section (except for the charge pump circuit), the shift register and the oscillator input buffer.
5	PSIF	I	Power saving mode control pin for the IF-PLL section. This pin must be set at "L" when the power supply is started up. (Open is prohibited.) $PS_{IF} = "H"$; Normal mode/ $PS_{IF} = "L"$; Power saving mode
6	VpiF		Power supply voltage input pin for the IF-PLL charge pump.
7	DOIF	0	Charge pump output for the IF-PLL section.
8	LD/fout	0	Lock detect signal output (LD) /phase comparator monitoring output (fout) pin. The output signal is selected by LDS bit in a serial data. LDS bit = "H" ; outputs fout signal/LDS bit = "L" ; outputs LD signal
9	DORF	0	Charge pump output for the RF-PLL section.
10	Vprf		Power supply voltage input pin for the RF-PLL charge pump.
11	PSrf	I	Power saving mode control for the RF-PLL section. This pin must be set at "L" when the power supply is started up. (Open is prohibited.) $PS_{RF} = "H"$; Normal mode/ $PS_{RF} = "L"$; Power saving mode
12	Vccrf		Power supply voltage input pin for the RF-PLL section (except for the charge pump circuit)
13	GNDRF		Ground pin for the RF-PLL section
14	Xfinrf	I	Prescaler complimentary input pin for the RF-PLL section. This pin should be grounded via a capacitor.
15	finrf	I	Prescaler input pin for the RF-PLL. Connection to an external VCO should be via AC coupling.
16	LE	I	Load enable signal input pin (with the schmitt trigger circuit) When LE is set "H", data in the shift register is transferred to the corresponding latch according to the control bit in a serial data.
17	Data	I	Serial data input pin (with the schmitt trigger circuit) Data is transferred to the corresponding latch (IF-ref. counter, IF-prog. counter, RF-ref. counter, RF-prog. counter) according to the control bit in a serial data.
18	Clock	I	Clock input pin for the 23-bit shift register (with the schmitt trigger circuit) One bit data is shifted into the shift register on a rising edge of the clock.
19	OSCIN	I	The programmable reference divider input pin. TCXO should be connected with an AC coupling capacitor.
20	GND		Ground pin for OSC input buffer and the shift register circuit.

BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Parame		Symbol	Rat	Unit	
Parame	eter	Symbol	Min	Max	Unit
Power aupply velter		Vcc	-0.5	4.0	V
Power supply voltage	5	Vp	Vcc	4.0	V
Input voltage		Vı	-0.5	Vcc + 0.5	V
Output voltage	LD/fout	Vo	GND	Vcc	V
Output voltage	DOIF, DORF	Vdo	GND	Vp	V
Storage temperature		Tstg	-55	+125	°C

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

■ RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol		Value	Unit	Remarks	
Farameter	Symbol	Min	Тур	Max	Onit	Remarks
Power supply voltage	Vcc	2.7	3.0	3.6	V	$V_{\text{CCRF}} = V_{\text{CCIF}}$
Power supply vollage	Vp	Vcc	3.0	3.6	V	
Input voltage	Vı	GND		Vcc	V	
Operating temperature	Та	-40		+85	°C	

Note : • VCCRF, VpRF, VCCIF and VpIF must supply equal voltage.

Even if either RF-PLL or IF-PLL is not used, power must be supplied to VCCRF, VpRF, VCCIF and VpIF to keep them equal.

It is recommended that the non-use PLL is controlled by power saving function.

- Although this device contains an anti-static element to prevent electrostatic breakdown and the circuitry has been improved in electrostatic protection, observe the following precautions when handling the device.
 - When storing and transporting the device, put it in a conductive case.
 - Before handling the device, confirm the (jigs and) tools to be used have been uncharged (grounded) as well as yourself. Use a conductive sheet on working bench.
 - Before fitting the device into or removing it from the socket, turn the power supply off.
 - When handling (such as transporting) the device mounted board, protect the leads with a conductive sheet.
- WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representatives beforehand.

■ ELECTRICAL CHARACTERISTICS

(Vcc = 2.7 V to 3.6 V, Ta = $-40 \degree C$ to $+85 \degree C$)

Devementer		Cumbal	Condition		Value		Unit	
Parameter		Symbol	Condition	Min	Тур	Max	Unit	
Dower ourply ourrent		ICCIF ^{*1}	finıғ = 2000 MHz V _{CCIF} = Vpıғ = 3.0 V	2.1	2.5	3.2	mA	
Power supply current		ICCRF ^{*1}	finrf = 2500 MHz Vccrf = Vprf = 3.0 V	5.7	6.5	8.4	mA	
Dower coving ourrent		PSIF	$PS_{IF} = PS_{RF} = "L"$		0.1 ^{*2}	10	μΑ	
Power saving current		IPSRF	$PS_{IF} = PS_{RF} = "L"$		0.1 ^{*2}	10	μΑ	
	fin⊧ *³	fin⊧	IF PLL	200		2000	MHz	
Operating frequency	fin _{RF} *3	finrf	RF PLL	2000		4000	MHz	
	OSCIN	fosc		3		40	MHz	
	fin⊧	Pfin⊧	IF PLL, 50 Ω system	-15		+2	dBm	
Input sensitivity	finrf	Pfinrf	RF PLL, 50 Ω system	-10		+2	dBm	
Input available voltage	OSCIN	Vosc		0.5		Vcc	V _P -p	
"H" level input voltage	Data LE	Vін	Schmitt trigger input	0.7 Vcc + 0.4			V	
"L" level input voltage	Clock	VIL	Schmitt trigger input			0.3 Vcc - 0.4	V	
"H" level input voltage	PSIF	Vih		0.7 Vcc			V	
"L" level input voltage	PS_{RF}	VIL	—			0.3 Vcc	V	
"H" level input current	Data LE	I ін ^{*4}		-1.0		+1.0	μΑ	
"L" level input current	Clock PS	 ı∟ ^{*4}		-1.0		+1.0	μΑ	
"H" level input current	OSCIN	Ін		0		+100	μΑ	
"L" level input current		I ⊫ ^{*4}	—	-100		0	μΑ	
"H" level output voltage	LD/	Vон	$V_{CC} = Vp = 3.0 V$, Iон = $-1 mA$	Vcc-0.4			V	
"L" level output voltage	fout	Vol	$V_{CC} = Vp = 3.0 V$, $I_{OL} = 1 mA$	—		0.4	V	
"H" level output voltage	DOIF	Vdoh	$V_{CC} = V_p = 3.0 \text{ V}, \text{ IDOH} = -0.5 \text{ mA}$	Vp - 0.4			V	
"L" level output voltage	DORF	Vdol	$V_{CC} = Vp = 3.0 \text{ V}, \text{ Idol} = 0.5 \text{ mA}$	—		0.4	V	
High impedance cutoff current	Doif Dorf	IOFF	$V_{CC} = Vp = 3.0 V$ $V_{OFF} = 0.5 V$ to $Vp - 0.5 V$			2.5	nA	
"H" level output current	LD/	І он ^{*4}	$V_{CC} = Vp = 3.0 V$	—		-1.0	mA	
"L" level output current	fout	Iol	$V_{CC} = Vp = 3.0 V$	1.0			mA	

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				-		Value		
Paramete	er	Symbol	Conditi	on	Min	Тур	Мах	Unit
"H" level output	DOIF *8	I*4	$V_{cc} = V_p = 3.0 \text{ V},$	CS bit = "H"	-8.2	-6.0	-4.1	mA
current	DORF	І дон ^{*4}	V _{DOH} = Vp / 2, Ta = +25 °C	CS bit = "L"	-2.2	-1.5	-0.8	mA
"L" level output	DOIF *8	la o:	$V_{cc} = V_p = 3.0 V,$	CS bit = "H"	4.1	6.0	8.2	mA
current	DORF	DOL	V _{DOL} = Vp / 2, Ta = +25 °C	CS bit = "L"	0.8	1.5	2.2	mA
	Idol/Idoh	DOMT *5	$V_{DO} = Vp / 2$		_	3	10	%
Charge pump	vs Vdo	DOVD *6	$0.5 \text{ V} \leq V_{DO} \leq Vp - 0$.5 V	_	10	15	%
current rate	vs Ta	Idota *7	$\begin{array}{l} -40 \ ^{\circ}C \leq Ta \leq 85 \ ^{\circ}C \\ V_{DO} = Vp \ / \ 2 \end{array}$	3		5	10	%

(Vcc = 2.7 V to 3.6 V, Ta = -40 °C to +85 °C)

*1 : Conditions ; fosc = 12.8 MHz, Ta = +25 °C, SW = "L" in locking state.

*2 : $V_{CCIF} = V_{PIF} = V_{CCRF} = V_{PRF} = 3.0 \text{ V}$, fosc = 12.8 MHz, Ta = +25 °C, in power saving mode. PSIF = PSRF = GND

 $V{\scriptscriptstyle I\!H}=V{\scriptscriptstyle C\!C},~V{\scriptscriptstyle I\!L}=GND$ (at CLK, Data, LE)

*3 : AC coupling. 1000 pF capacitor is connected under the condition of Min operating frequency.

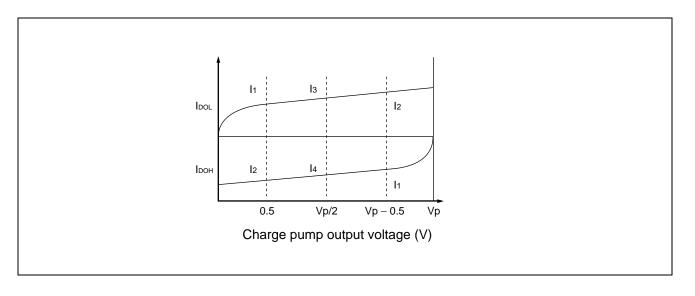
*4 : The symbol "--" (minus) means the direction of current flow.

*5 : Vcc = Vp = 3.0 V, Ta = +25 °C ($||I_3| - |I_4||$) / [($|I_3| + |I_4|$) / 2] × 100 (%)

*6 : $V_{CC} = V_p = 3.0 \text{ V}$, Ta = +25 °C [(||I₂| - ||I₁|) / 2] / [(|I₁| + |I₂|) / 2] × 100 (%) (Applied to both IDOL and IDOH)

*7 : Vcc = Vp = 3.0 V, [||Ioo (+85 °C) | - |Ioo (-40 °C) || / 2] / [|Ioo (+85 °C) | + |Ioo (-40 °C) | / 2] × 100 (%) (Applied to both IooL and IooH)

*8 : When Charge pump current is measured, set LDS = "L", T1 = "L" and T2 = "H".



■ FUNCTIONAL DESCRIPTION

1. Pulse swallow function

 $f_{VCO} = [(P \times N) + A] \times f_{OSC} \div R$

- fvco : Output frequency of external voltage controlled oscillator (VCO)
- P : Preset divide ratio of dual modulus prescaler (32 or 64 for IF-PLL, 64or 128 for RF-PLL)
- N : Preset divide ratio of binary 11-bit programmable counter (3 to 2,047)
- A : Preset divide ratio of binary 7-bit swallow counter (0 \leq A \leq 127, A < N)
- fosc : Reference oscillation frequency (OSC_{IN} input frequency)
- R : Preset divide ratio of binary 14-bit programmable reference counter (3 to 16,383)

2. Serial Data Input

The serial data is entered using three pins, Data pin, Clock pin, and LE pin. Programmable dividers of IF/RF-PLL sections, programmable reference dividers of IF/RF-PLL sections are controlled individually.

The serial data of binary data is entered through Data pin.

On rising edge of Clock, one bit of the serial data is transferred into the shift register. On a rising edge of load enable signal, the data stored in the shift register is transferred to one of latches depending upon the control bit data setting.

	The programmable reference counter for the IF-PLL	The programmable reference counter for the RF-PLL	The programmable counter and the swallow counter for the IF-PLL	The programmable counter and the swallow counter for the RF-PLL
CN1	0	1	0	1
CN2	0	0	1	1

(1) Shift Register Configuration

• Programmable Reference Counter

(LSB)									Dat	a Flo	W						(M	ISB)				
1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21	22	23
CN1	CN2	T1	T2	R1	R2	R3	R4	R5	R6	R7	R8	R9	R10	R11	R12	R13	R14	CS	Х	Х	Х	Х

CS: Charge pump current select bitR1 to R14: Divide ratio setting bits for the programmable reference counter (3 to 16,383)T1, 2: LD/fout output setting bitCN1, 2: Control bitX: Dummy bits (Set "0" or "1")

Note : Data input with MSB first.

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• F	Programmable Counter																					
	(L\$	SB)			Data Flow ———							(MSB)										
1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21	22	23
CN1	CN2	LDS	SWif/ RF	FCIF/	A1	A2	A3	A4	A5	A6	A7	N1	N2	N3	N4	N5	N6	N7	N8	N9	N10	N11
		LDS SWIF FCIF/ CN1	D N11 / _{RF} / _{RF}	: Divid : Divid : LD/fc : Divid : Phas : Conti	e rat out s e rat se co rol b	tio s igna tio s ontro it	ettin I sel ettin I bit	g bit ect k g bit	s for bit for f	[.] the the p	prog prese	gram calei	nmal r (IF	ble c : SV	oun Vif, F	ter (: RF :	3 to SWr	RF)	7)			

(2) Data setting

• Binary 14-bit Programmable Reference Counter Data Setting

Divide ratio	R14	R13	R12	R11	R10	R9	R8	R7	R6	R5	R4	R3	R2	R1
3	0	0	0	0	0	0	0	0	0	0	0	0	1	1
4	0	0	0	0	0	0	0	0	0	0	0	1	0	0
•	•	•	•	•	•	•	•	•	•	•	•	•	•	•
•	•	•	•	•	•	•	•	•	•	•	•	•	•	•
16383	1	1	1	1	1	1	1	1	1	1	1	1	1	1

Note : Divide ratio less than 3 is prohibited.

 Binary 	/ 11-bit Programmable Count	er Data Setting
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Divide ratio	N11	N10	N9	N8	N7	N6	N5	N4	N3	N2	N1
3	0	0	0	0	0	0	0	0	0	1	1
4	0	0	0	0	0	0	0	0	1	0	0
•	•	•	٠	٠	•	٠	٠	•	٠	٠	•
•	•	•	•	•	•	•	•	•	•	•	•
2047	1	1	1	1	1	1	1	1	1	1	1

Note : Divide ratio less than 3 is prohibited

• Binary 7-bit Swallow Counter Data Setting

							-
Divide ratio	A7	A6	A5	A4	A3	A2	A1
0	0	0	0	0	0	0	0
1	0	0	0	0	0	0	1
•	•	•	•	•	•	•	•
•	٠	•	•	٠	٠	•	•
•	•	•	•	•	•	•	•
127	1	1	1	1	1	1	1

• Prescaler Data Setting

Divide ratio	SW = "H"	SW = "L"
Prescaler divide ratio IF-PLL	32/33	64/65
Prescaler divide ratio RF-PLL	64/65	128/129

Charge Pump Current Setting

Current value	CS
±6.0 mA	1
±1.5 mA	0

• LD/fout output Selectable Bit Setting

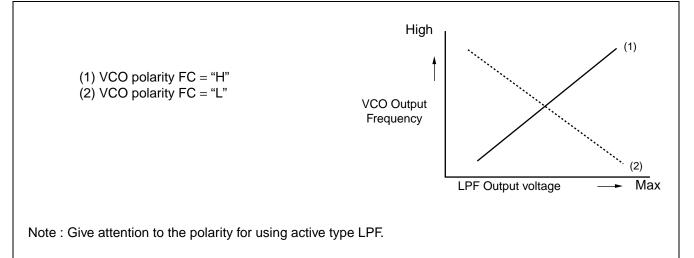
LD/fout	pin state	LDS	T1	T2
LD output		0	0	0
		0	1	0
		0	1	1
fout output	frı⊧	1	0	0
	fr RF	1	1	0
	fpı⊧	1	0	1
	fprf	1	1	1

Phase Comparator Phase Switching Data Setting

Phase comparator input	FCIF, RF = "H"	FCIF, RF = "L"
	Doif, rf	DOIF, RF
fr > fp	Н	L
fr < fp	L	Н
fr = fp	Z	Z

Z : High-impedance

Depending upon the VCO and LPF polarity, FC bit should be set.



3. Power Saving Mode (Intermittent Mode Control Circuit)

Status	PS pin
Normal mode	Н
Power saving mode	L

The intermittent mode control circuit reduces the PLL power consumption.

By setting the PS pin low, the device enters into the power saving mode, reducing the current consumption. See the Electrical Characteristics chart for the specific value.

The phase detector output, Do, becomes high impedance.

For the dual PLL, the lock detector, LD, is as shown in the LD Output Logic table.

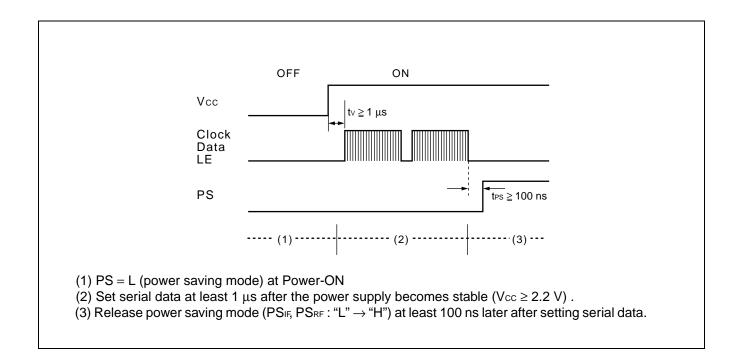
Setting the PS pin high, releases the power saving mode, and the device works normally.

The intermittent mode control circuit also ensures a smooth startup when the device returns to normal operation. When the PLL is returned to normal operation, the phase comparator output signal is unpredictable. This is because of the unknown relationship between the comparison frequency (fp) and the reference frequency (fr) which can cause a major change in the comparaor output, resulting in a VCO frequency jump and an increase in lockup time.

To prevent a major VCO frequency jump, the intermittent mode control circuit limits the magnitude of the error signal from the phase detector when it returns to normal operation.

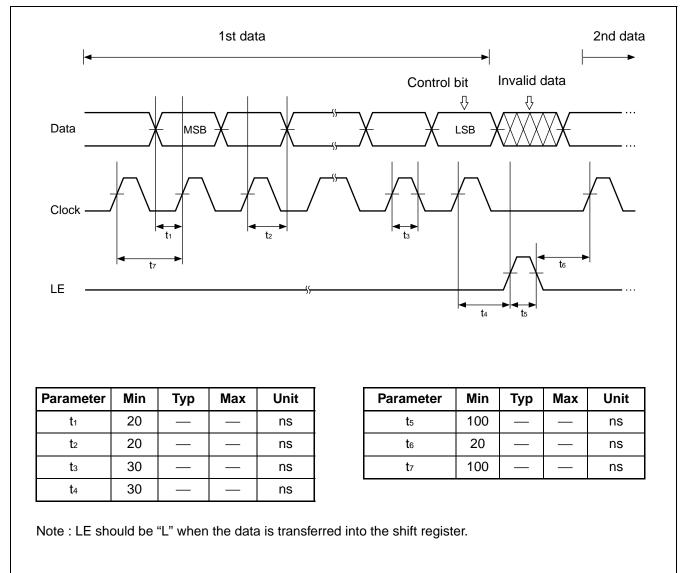
Notes : • When power (VCC) is first applied, the device must be in standby mode.

• PS pin must be set "L" at Power-ON.



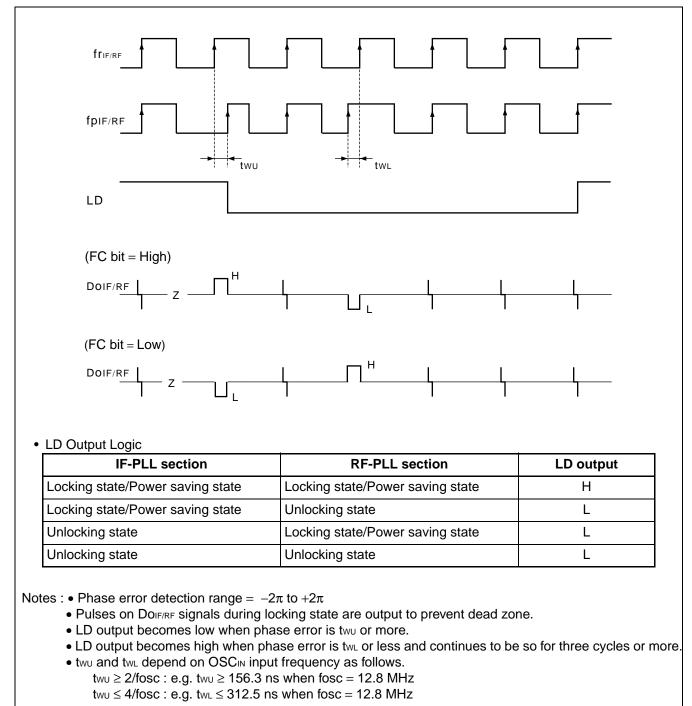
4. Serial Data Data Input Timing

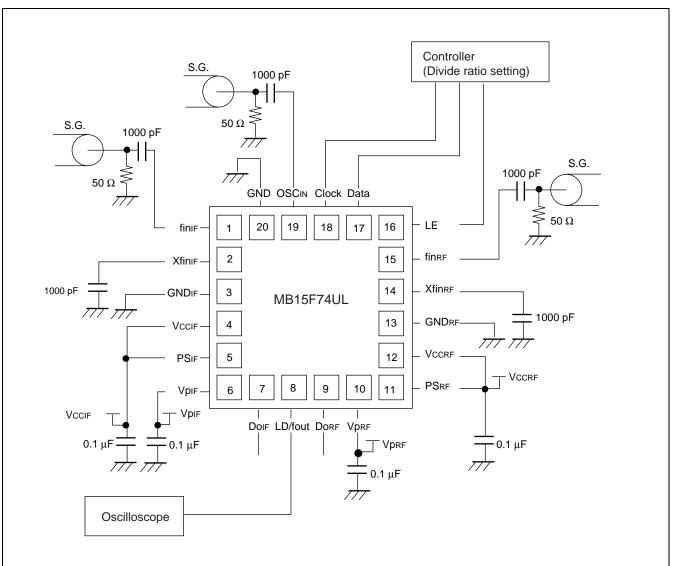
Divide ratio is performed through a serial interface using the Data pin, Clock pin, and LE pin. Setting data is read into the shift register at the rise of the Clock signal, and transferred to a latch at the rise of the LE signal. The following diagram shows the data input timing.



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■ PHASE COMPARATOR OUTPUT WAVEFORM

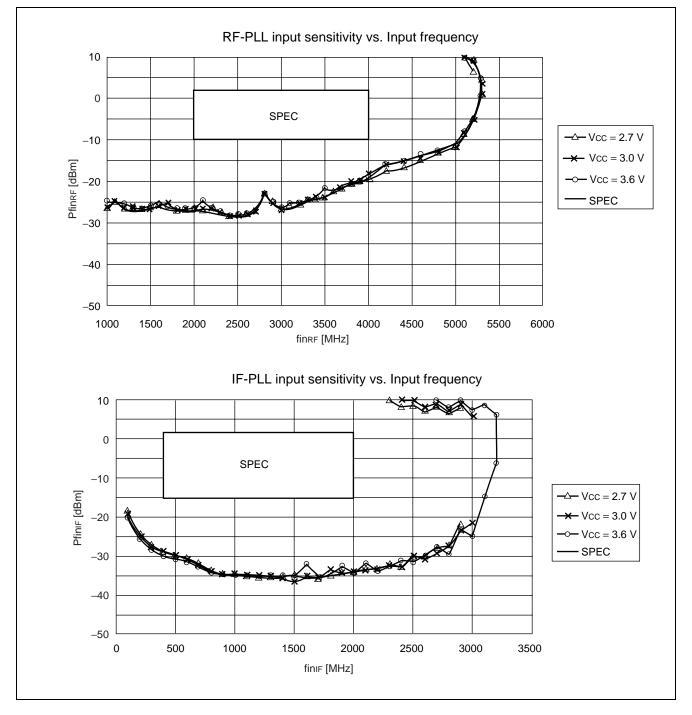




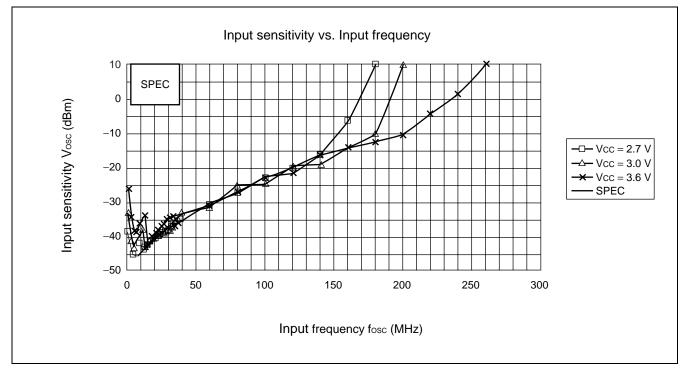
■ TEST CIRCUIT (for Measuring Input Sensitivity fin/OSC_{IN})

■ TYPICAL CHARACTERISTICS

1. fin input sensitivity

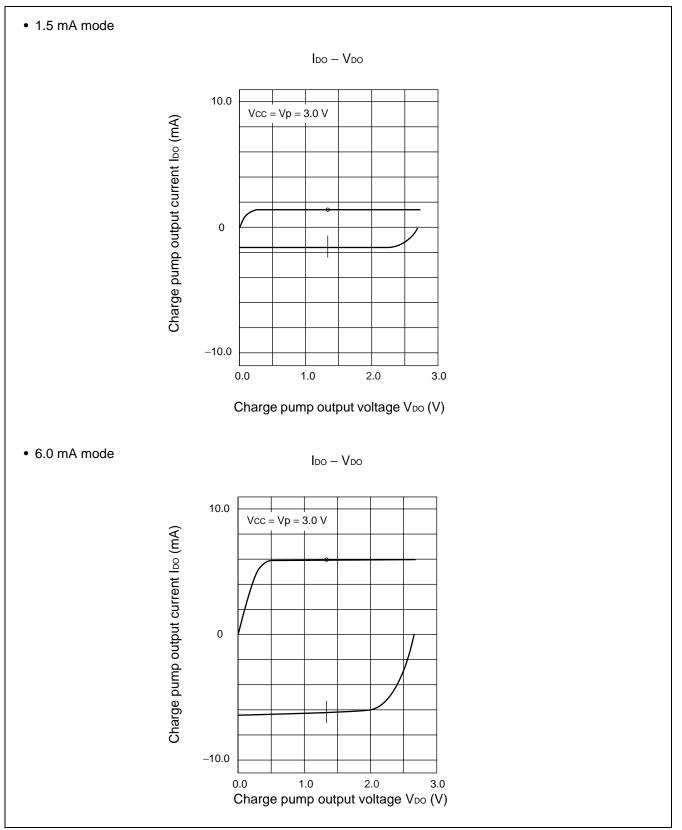


2. OSCIN input sensitivity

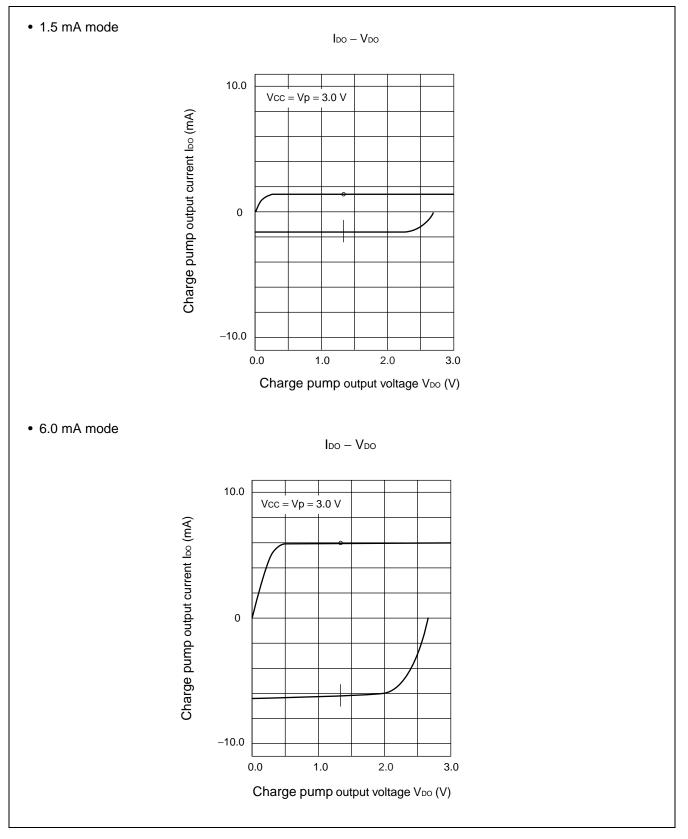


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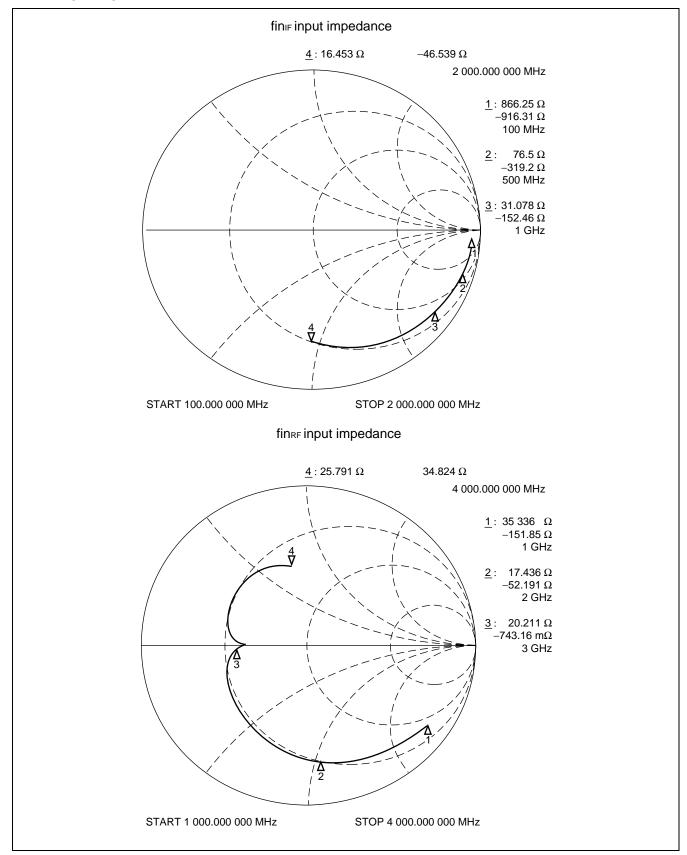
3. RF-PLL Do output current



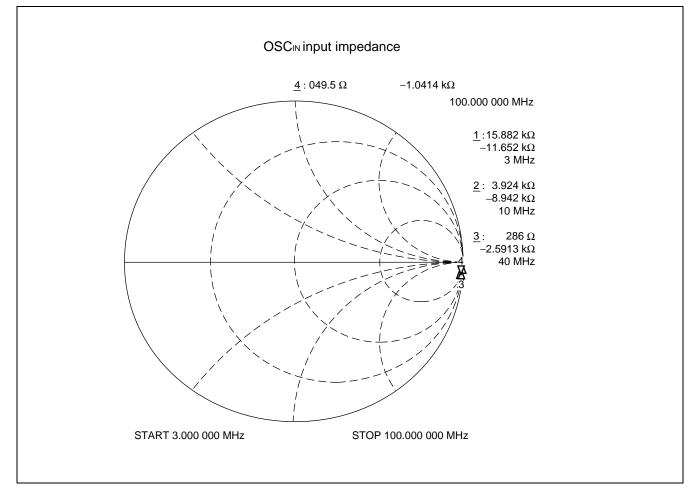
4. IF-PLL Do output current



5. fin input impedance

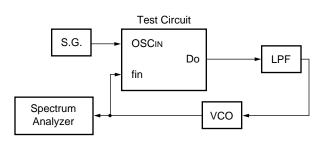


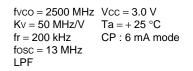
6. OSCIN input impedance

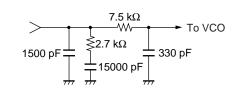


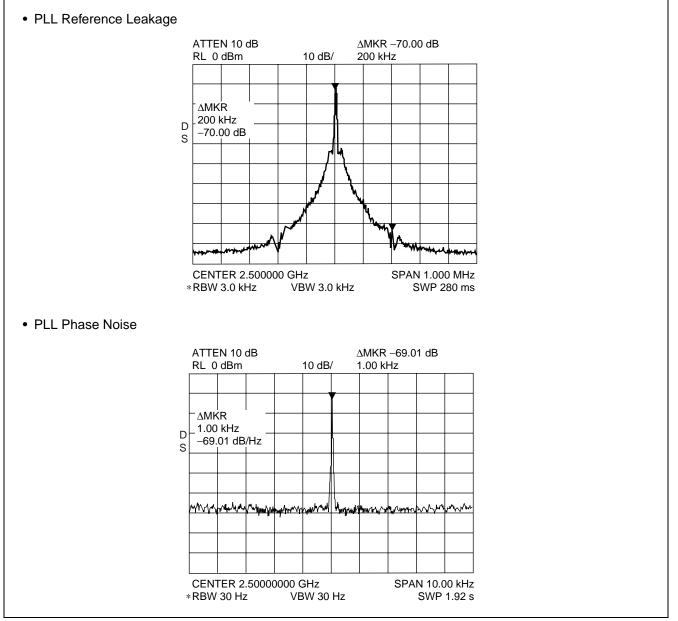
■ REFERENCE INFORMATION

(for Lock-up Time, Phase Noise and Reference Leakage)



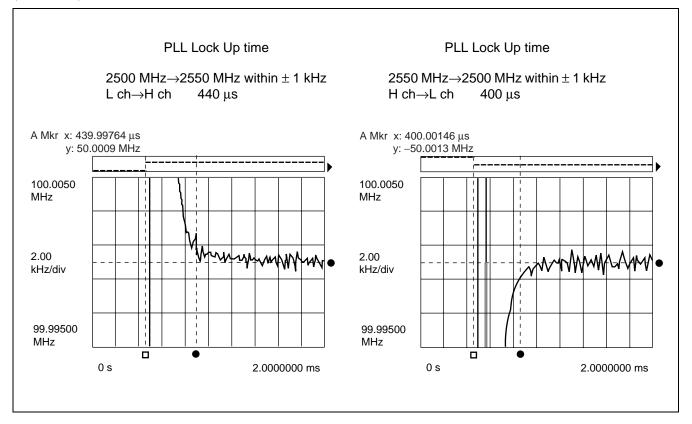






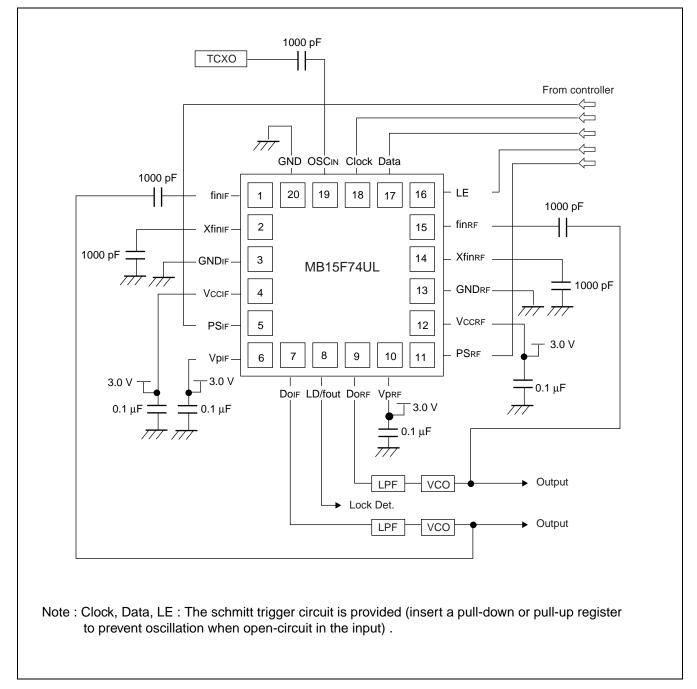
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■ APPLICATION EXAMPLE



■ USAGE PRECAUTIONS

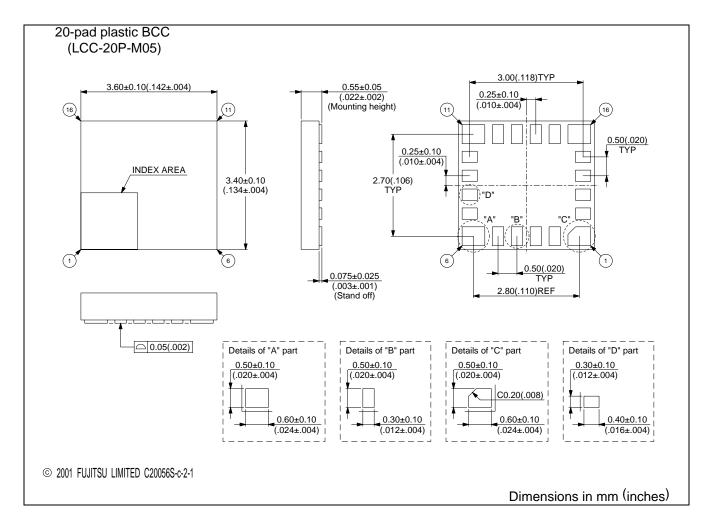
(1) V_{CCRF}, V_{PRF}, V_{CCIF} and V_{PIF} must be equal voltage. Even if either RF-PLL or IF-PLL is not used, power must be supplied to V_{CCRF}, V_{PRF}, V_{CCIF} and V_{PIF} to keep them equal. It is recommended that the non-use PLL is controlled by power saving function.

- (2) To protect against damage by electrostatic discharge, note the following handling precautions :
 - Store and transport devices in conductive containers.
 - Use properly grounded workstations, tools, and equipment.
 - Turn off power before inserting or removing this device into or from a socket.
 - Protect leads with conductive sheet, when transporting a board mounted device

■ ORDERING INFORMATION

Part number	Package	Remarks
MB15F74ULPVA	20-pad plastic BCC (LCC-20P-M05)	

■ PACKAGE DIMENSION



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